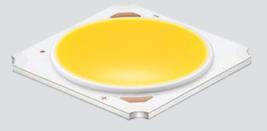
# High Voltage LED Series Chip on Board

LCo33B Gen.2



# High efficacy COB LED package, well-suited for use in spotlight applications

#### **Features & Benefits**

- Chip on Board (COB) solution makes it easy to design in
- Simple assembly reduces manufacturing cost
- Low thermal resistance
- InGaN/GaN MQW LED with long time reliability
- Completed 6,000 hours of LM-80 Testing
- ENEC certified: Integral LED Module

#### **Applications**

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination



c Sus



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#### **1.** Characteristics

#### a) Absolute Maximum Rating

ltem	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	Ta	-40 ~ +105	٥C	-
Storage Temperature	T <sub>stg</sub>	-40 ~ +120	٥C	-
LED Junction Temperature	Tj	150	٥C	-
Case Temperature	Тс	105	٥C	*Note
Forward Current	I <sub>F</sub>	1620	mA	-
Power Dissipation	P <sub>D</sub>	59.9	W	-
ESD (HBM)	-	±2	kV	-
ESD (MM)	-	±0.5	kV	-

#### b) Electro-optical Characteristics $(I_F = 900 \text{ mA}, T_c = 25 \text{ }^{\circ}\text{C})$

ltem	Unit	Rank	Min.	Тур.	Max.
Forward Voltage (V <sub>F</sub> )	V	YH	32.5	35.5	38.5
		3	70	-	-
Color Rendering Index (R <sub>a</sub> )	-	5	80 ( R9 > 0 )	-	-
		7	90	-	-
Thermal Resistance (junction to chip point)	°C/W		-	0.9	-
Beam Angle	0		-	115	-
Nominal Power	W			32.0	
Eye Protection	0	Risk 1	-		-

#### Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ( $T_j = T_c = T_a = 25$  °C)
- 2) Samsung maintains measurement tolerance of: forward voltage =  $\pm$ 5 %, CRI =  $\pm$ 1
- 3) Max Tc=105 Pently is now EWEC condition. Refer to the derating curve, '3. Typical Characteristics Graph' designed within the range.



#### c) Luminous Flux Characteristics ( $I_F = 900 \text{ mA}$ )

CRI (R <sub>a</sub> )	Nominal	Flux	Flux	Sorting <sup>1)</sup> @	T <sub>c</sub> = 25 °C (lm)	Calculated Flux <sup>2)</sup>	@ T <sub>c</sub> = 85 °C (Im
Min.	CCT (K)	Rank	Bin	Min.	Max.	Min.	Max.
	2000	40	41	4021	4570	3619	4113
	3000	4P	42	4570	5118	4113	4606
70		15	41	4222	4798	3800	4318
70	4000	4P	42	4798	5374	4318	4836
	5000	45	41	4262	4844	3836	4359
	5000	4P	42	4844	5425	4359	4882
			41	4210	4485	3831	4081
	2700	3G	42	4485	4761	4081	4332
		ЗH	42	4485	4761	4081	4332
			41	4478	4771	4075	4342
	3000	3G	42	4771	5064	4342	4609
		ЗH	42	4771	5064	4342	4609
			41	4613	4915	4198	4472
	3500	3G	42	4915	5216	4472	4747
		3H	42	4915	5216	4472	4747
80	4000	_	40	4437	4747	4037	4320
		3G	41	4747	5058	4320	4603
		ЗH	41	4747	5058	4320	4603
	5000		40	4478	4792	4075	4361
		3G	41	4792	5105	4361	4646
		ЗH	41	4792	5105	4361	4646
			40	4478	4792	4075	4361
	5700	3G	41	4792	5105	4361	4646
		ЗH	41	4792	5105	4361	4646
			33	3527	3810	3210	3467
	2700	3Q	34	3810	4200	3467	3822
		<u></u>	33	3599	3887	3276	3538
0.0	3000	3Q	34	3887	4277	3538	3892
90		<u></u>	33	3707	4004	3374	3644
	3500	3Q	34	4004	4394	3644	3999
	4000	<u></u>	33	3815	4121	3472	3750
	4000	3Q	34	4121	4511	3750	4105
	0700	0.1	31	2857	3175	2600	2889
	2700	3J	32	3175	3492	2889	3178
			31	2946	3273	2681	2978
95	3000	3J	32	3273	3600	2978	3276
			31	3034	3371	2761	3068
	3500	3J	32	3371	3708	3068	3375

#### Notes:

1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ( $T_j = T_c = T_a = 25$  °C)

2) Calculated flux values are for reference only

3) Samsung maintains measurement tolerance of: luminous flux =  $\pm$ 7 %, CRI =  $\pm$ 1



#### 2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S																	

Digit	PKG Information	Code				Specificat	ion
1 2 3	Samsung Package High Power	SPH					
4 5	Color	ww	Warm White	(T/U/	V/W Rank	s)	
4 5	COIOI	CW	Cool White	(Q/R	Ranks)		
6	Product Version	1					
78	Form Factor	HD	СОВ				
9	Lens Type	Ν	No lens				
10	Internal Code	D	LC033				
11	Chip Type	2					
		3	Min. 70				
12	CRI & Sorting Temperature	5	Min. 80	5 °C			
		7	Min. 90				
		8	Min 95				
13 14	Forward Voltage (V)	YH	32.5~38.5				
		w	2700 K		WA,WB	(MacAdam Ellipse)	
		V	3000 K		VA, VB	(MacAdam Ellipse)	VW, VX, VY, VZ (ANSI bin)
15	CCT (K)	U		Bin	UA, UB	(MacAdam Ellipse)	
15		т	4000 K	ode:	TA, TB	(MacAdam Ellipse)	TW, TX, TY, TZ (ANSI bin)
		R	5000 K		RA	(MacAdam Ellipse)	RW, RX, RY, RZ (ANSI bin)
		Q	5700 K				QW, QX, QY, QZ (ANSI bin)
		2	MacAdam 2-s	step			
16	MacAdam / ANSI	3	MacAdam 3-s	step			
		Т	ANSI bin				
		3J			31, 32 (	95 CRI)	
		3G			40, 41, 42	(80 CRI)	
17 18	Luminous Flux	ЗH		Bin ode:	41, 42 (8	30 CRI)	
		3Q			33, 34 (	90 CRI)	
		4P			41, 42 (	70 CRI)	



## a) Binning Structure (I<sub>F</sub> = 900 mA, $T_c = 25 \ ^{\circ}C$ )

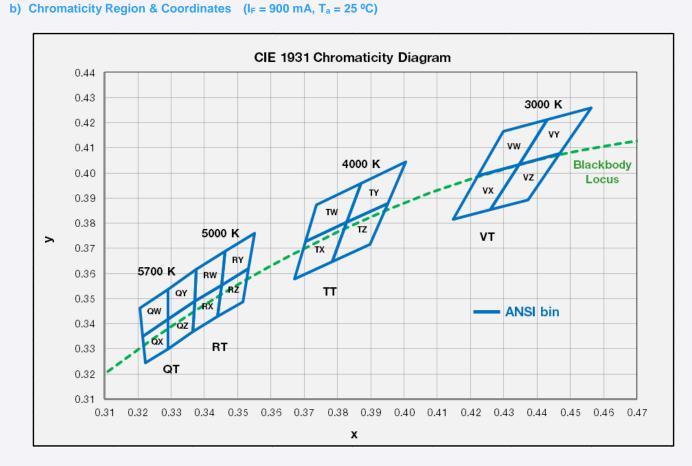
CRI (R <sub>a</sub> ) Min.	Nominal CCT (K)	Product Code	V <sub>F</sub> Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ <sub>v</sub> , lm)		
	3000		ΥH	VT	VW, VX	4P	41	4021 ~ 4570		
	3000	SPHWW1HDND23YHVT4P	ĭΠ	VI	VY, VZ	48	42	4570 ~ 5118		
70	4000		VII		TW, TX	4P	41	4222 ~ 4798		
70	4000	SPHWW1HDND23YHTT4P	ΥH	TT	TY, TZ	48	42	4798 ~ 5374		
	5000		YH	DT	RW, RX	4P	41	4262 ~ 4844		
	5000	SPHCW1HDND23YHRT4P	ТП	RT	RY, RZ	4	42	4844 ~ 5425		
		SPHWW1HDND25YHW23G	ΥH	W2	WB	3G	41	4210 ~ 4485		
		3FHWW1HDND231HW23G	ТП	VVZ	VVD	30	42	4485 ~ 4761		
	2700		ΥH	W3	WA, WB	3G	41	4210 ~ 4485		
	2700	SPHWW1HDND25YHW33G	ТП	VV3	WA, WD	30	42	4485 ~ 4761		
		SPHWW1HDND25YHW23H	YH	W2	WB	3H	42	4485 ~ 4761		
		SPHWW1HDND25YHW33H	YH	W3	WA, WB	3H	42	4485 ~ 4761		
			VII		VD	20	41	4478 ~ 4771		
		SPHWW1HDND25YHV23G	YH	V2	VB	3G	42	4771 ~ 5064		
	2000		N/L1				41	4478 ~ 4771		
	3000	SPHWW1HDND25YHV33G	ΥH	V3	VA, VB	3G	42	4771 ~ 5064		
		SPHWW1HDND25YHV23H	YH	V2	VB	ЗH	42	4771 ~ 5064		
		SPHWW1HDND25YHV33H	YH	V3	VA, VB	ЗH	42	4771 ~ 5064		
					115		41	4613 ~ 4915		
		SPHWW1HDND25YHU23G	YH	U2	UB	3G	42	4915 ~ 5216		
	2500		N/L I			20	41	4613 ~ 4915		
	3500  	SPHWW1HDND25YHU33G	ΥH	U3	UA, UB	3G	42	4915 ~ 5216		
			-	SPHWW1HDND25YHU23H	YH	U2	UB	3H	42	4915 ~ 5216
80		SPHWW1HDND25YHU33H	YH	U3	UA, UB	ЗH	42	4915 ~ 5216		
							40	4437 ~ 4747		
		SPHWW1HDND25YHT23G	YH	T2	ТВ	3G	41	4747 ~ 5058		
							40	4437 ~ 4747		
	4000	SPHWW1HDND25YHT33G	YH	Т3	TA, TB	3G	41	4747 ~ 5058		
		SPHWW1HDND25YHT23H	YH	T2	TB	3H	41	4747 ~ 5058		
	-	SPHWW1HDND25YHT33H	YH	Т3	TA, TB	3H	41	4747 ~ 5058		
				_		_	40	4478 ~ 4792		
		SPHCW1HDND25YHR33G	YH	R3	RA	3G	41	4792 ~ 5105		
					RW, RX,		40	4478 ~ 4792		
	5000	SPHCW1HDND25YHRT3G	YH	RT	RY, RZ	3G	41	4792 ~ 5105		
	-	SPHCW1HDND25YHR33H	YH	R3	RA	ЗH	41	4792 ~ 5105		
		SPHCW1HDND25YHRT3H	ΥH	RT	RW, RX, RY, RZ	ЗH	41	4792 ~ 5105		
					QW, QX		40	4478 ~ 4792		
	E700	SPHCW1HDND25YHQT3G	YH	QT	QY, QZ	3G	41	4792 ~ 5105		
	5700	SPHCW1HDND25YHQT3H	YH	QT	QW, QX QY, QZ	3H	41	4792 ~ 5105		



# a) Binning Structure $(I_F = 900 \text{ mA}, T_c = 25 \text{ °C})$

CRI (R₃) Min.	Nominal CCT (K)	Product Code	V <sub>F</sub> Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ <sub>v</sub> , Im)
		SPHWW1HDND27YHW23Q	YH	W2	WB	3Q	33	3527 ~ 3810
	2700	SPRWWIRDNOZ/TRWZSQ	ГП	VVZ	VVD	30	34	3810 ~ 4200
	2700	SPHWW1HDND27YHW33Q	YH	W3	WA, WB	3Q	33	3527 ~ 3810
		3F11WW111DND27111W33Q		vv3	VVA, VVD	50	34	3810 ~ 4200
		SPHWW1HDND27YHV23Q	ΥH	V2	VB	3Q	33	3599 ~ 3887
	3000	SFIIWWIIIDND27111V23Q		٧Z	VD	50	34	3887 ~ 4277
	3000	SPHWW1HDND27YHV33Q	YH	V3		3Q	33	3599 ~ 3887
90		SFIIWWIIIDND27111033Q		v 3	VA, VB	50	34	3887 ~ 4277
90		SPHWW1HDND27YHU23Q	YH	U2	UB	3Q	33	3707 ~ 4004
	3500	SERVINI INDIVIZI TRUZSQ	гп	02	UB	30	34	4004 ~ 4394
	3500	SPHWW1HDND27YHU33Q	YH	U3	UA, UB	3Q	33	3707 ~ 4004
		SERVIN INDIVUZI INUSSQ	ГП	03	UA, UB	30	34	4004 ~ 4394
		SPHWW1HDND27YHT23Q	YH	T2	ТВ	3Q	33	3815 ~ 4121
	4000	SPRWWIRDND2/TR123Q	ΪΠ	12	IВ	30	34	4121 ~ 4511
	4000	SPHWW1HDND27YHT33Q	YH	T3	та тр	20	33	3815 ~ 4121
		SPRIMINDIND2/11133Q	ГП	15	TA, TB	3Q	34	4121 ~ 4511
		SPHWW1HDND28YHW23J	ΥH	W2	WB	21	31	2857 ~ 3175
	2700	SPRWWINDND28TRW23J	ΪΠ	VVZ		3J	32	3175 ~ 3492
	2700		VII	14/2		21	31	2857 ~ 3175
		SPHWW1HDND28YHW33J	YH	W3	WA,WB	3J	32	3175 ~ 3492
			VU	1/0		21	31	2946 ~ 3273
05	2000	SPHWW1HDND28YHV23J	YH	V2	VB	3J	32	3273 ~ 3600
95	3000		N/L1			21	31	2946 ~ 3273
		SPHWW1HDND28YHV33J	ΥH	V3	VA,VB	3J	32	3273 ~ 3600
			N/LI			21	31	3034 ~ 3371
	2500	SPHWW1HDND28YHU23J	YH	U2	UB	3J	32	3371 ~ 3708
	3500		N/LL			21	31	3034 ~ 3371
		SPHWW1HDND28YHU33J	YH	U3	UA,UB	ЗJ	32	3371 ~ 3708



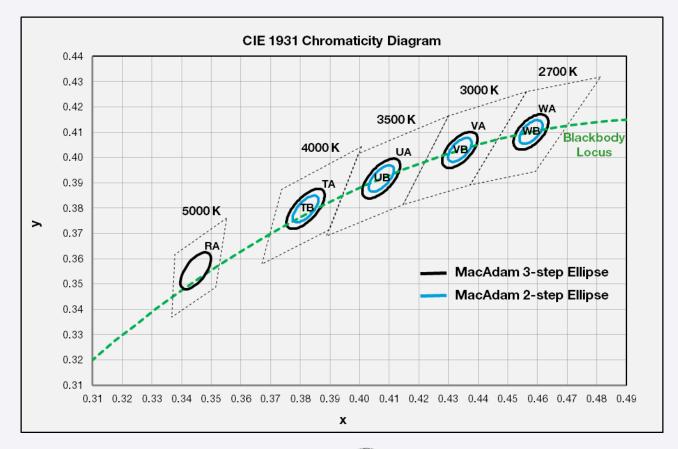


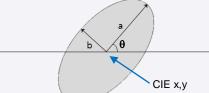
Region	CIE x	CIE y	Region	CIE x	CIE y
		V rank	(3000 K)		
	0.4223	0.3990		0.4345	0.4033
VW	0.4345	0.4033	VY	0.4468	0.4077
VVV	0.4431	0.4213	VY	0.4562	0.4260
	0.4299	0.4165		0.4431	0.4213
	0.4223	0.3990		0.4260	0.3854
	0.4147	0.3814	VZ	0.4373	0.3893
VX	0.4260	0.3854		0.4468	0.4077
	0.4345	0.4033		0.4345	0.4033
		R rank	(5000 K)		
	0.3376	0.3616		0.3463	0.3687
DW	0.3463	0.3687	DV	0.3551	0.3760
RW	0.3451	0.3554	RY	0.3533	0.3620
	0.3371	0.3490		0.3451	0.3554
	0.3371	0.3490		0.3451	0.3554
DV	0.3451	0.3554	57	0.3533	0.3620
RX	0.3440	0.3428	RZ	0.3515	0.3487
	0.3366	0.3369		0.3440	0.3428

Region	CIE x	CIE y	Region	CIE x	CIE y
		T rank	(4000 K)		
	0.3736	0.3874		0.3871	0.3959
77.47	0.3871	0.3959		0.4006	0.4044
TW	0.3828	0.3803	ΤY	0.3952	0.3880
	0.3703	0.3726		0.3828	0.3803
	0.3703	0.3726		0.3828	0.3803
ТХ	0.3828	0.3803	ΤZ	0.3952	0.3880
IX	0.3784	0.3647		0.3898	0.3716
	0.3670	0.3578		0.3784	0.3647
		Q rank	(5700 K)		
	0.3207	0.3462		0.3290	0.3538
QW	0.3290	0.3538	<u></u>	0.3376	0.3616
QW	0.3290	0.3417	QY	0.3371	0.3490
	0.3215	0.3350		0.3290	0.3417
	0.3215	0.3350		0.3290	0.3417
QX	0.3290	0.3417	QZ	0.3371	0.3490
QX	0.3290	0.3300	QΖ	0.3366	0.3369
	0.3222	0.3243		0.3290	0.3300









MacAdam Ellipse (WA, WB)										
Step	CIE x	CIE y								
2-step	0.4578	0.4101	53.70	0.0054	0.0028					
3-step	0.4578	0.4101	53.70	0.0081	0.0042					

MacAdam Ellipse (UA, UB)										
Step	CIE x	CIE y								
2-step	0.4073	0.3917	54.00	0.0062	0.0028					
3-step	0.4073	0.3917	54.00	0.0093	0.0041					

MacAdam Ellipse (RA)						
Step CIE x CIE y θ a b						
3-step 0.3447 0.3553 59.62 0.0082 0.0035						

#### Note:

Samsung maintains measurement tolerance of: Cx,  $Cy = \pm 0.005$ 

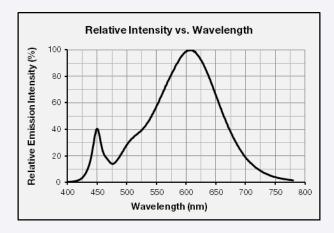
MacAdam Ellipse (VA, VB)									
Step CIE x CIE y θ a b									
2-step	0.4338	0.4030	53.22	0.0056	0.0027				
3-step	3-step 0.4338 0.4030 53.22 0.0083 0.0041								

MacAdam Ellipse (TA, TB)									
Step	Step CIE x CIE y θ a b								
2-step	0.3818	0.3797	53.72	0.0063	0.0027				
3-step	3-step 0.3818 0.3797 53.72 0.0094 0.0040								



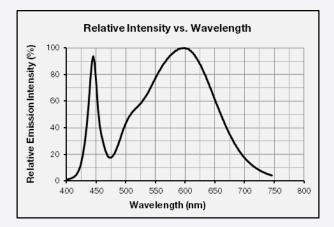
#### 3. Typical Characteristics Graphs

#### a) Spectrum Distribution ( $I_F = 900 \text{ mA}, T_c = 25 \text{ °C}$ )

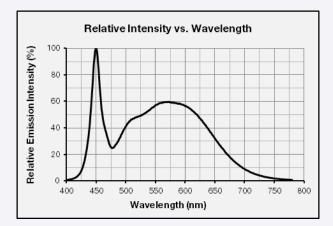


CCT: 3500 K

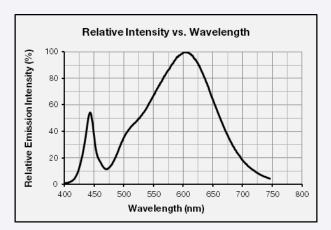
CCT: 2700 K



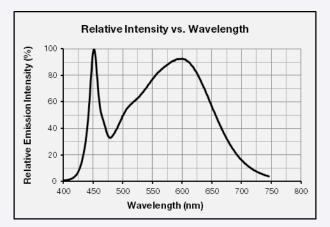




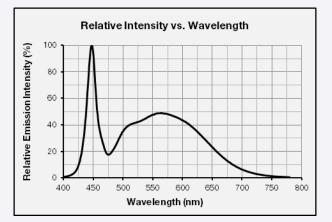
CCT: 3000 K



CCT: 4000 K

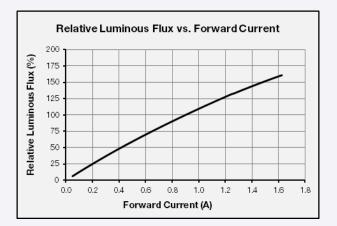


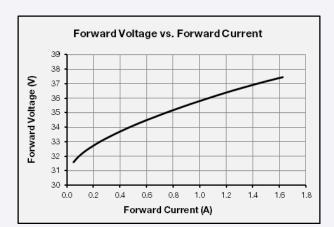
ССТ: 5700 К



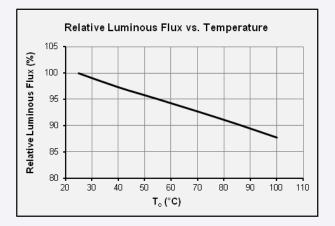






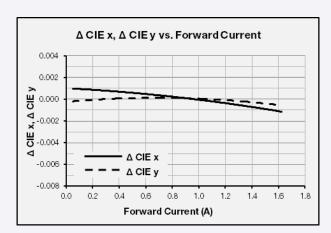


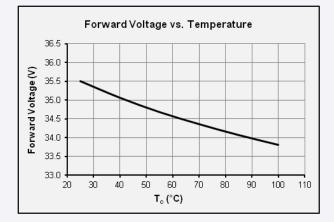
#### c) Temperature Characteristics (I<sub>F</sub> = 900 mA)



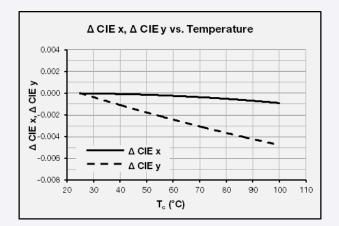


T<sub>c</sub> = 25 °C



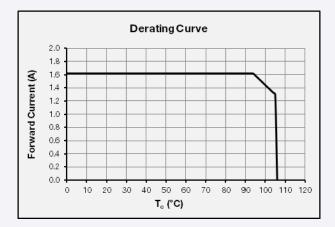




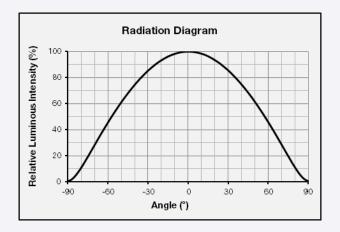




#### e) Derating Curve

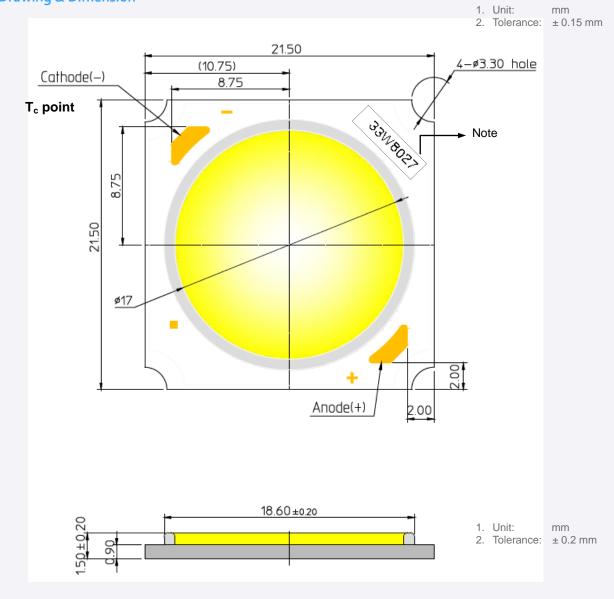


#### f) Beam Angle Characteristics ( $I_F = 900 \text{ mA}, T_c = 25 \text{ °C}$ )





# 4. Outline Drawing & Dimension



ltem	Dimension	Tolerance	Unit
Length	21.50	±0.15	mm
Width	21.50	±0.15	mm
Height	1.50	±0.20	mm
Light Emitting Surface (LES) Diameter	17	±0.15	mm

Note: Denoted product information above is only an example ( 33W8027 : 33W, CRI80+, 2700K )



# 5. Reliability Test Items & Conditions

#### a) Test Items

Test Item	Test Condition	Test Hour / Cycle
Room Temperature Life Test	25 °C, I <sub>F</sub> = max	1000 h
High Temperature Humidity Life Test	85 °C, 85 % RH, DC Derating, $I_F$ = max	1000 h
High Temperature Life Test	105 °C, DC Derating, $I_F = max$	1000 h
Low Temperature Life Test	-40 °C, DC 1620 mA	1000 h
High Temperature Storage	120 °C	1000 h
Low Temperature Storage	-40 °C	1000 h
Thermal Shock	-45 ºC / 15 min ↔ 125 ºC / 15 min temperature change in 5 min	200 cycles
Temperature Cycle On/Off Test	-40 °C / 85 °C each 20 min, 100 min transfer power on/off each 5 min, DC 900 mA	100 cycles
Temperature Humidity Storage Test	-10 °C ↔ 25 °C, 95 % RH ↔ 85 °C, 95 % RH (24 h / cycle)	100 cycles
ESD (HBM)	R <sub>1</sub> : 10 MΩ R <sub>2</sub> : 1.5 kΩ C: 100 pF V: ±2 kV	5 times
ESD (MM)	R <sub>1</sub> : 10 MΩ R <sub>2</sub> : 0 kΩ C: 200 pF V: ±0.5 kV	5 times
Vibration Test	20 ~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔ max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500 g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Salt Spray Test	35 ℃, 5 % salt water 8 h spray, 16 h dwell	2 cycles

## b) Criteria for Judging the Damage

ltem	Symbol	Test Condition	Limit		
item	Зуньог	(T <sub>c</sub> = 25 °C)	Min.	Max.	
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 900 mA	L.S.L. * 0.9	U.S.L. * 1.1	
Luminous Flux	$\Phi_{v}$	I <sub>F</sub> = 900 mA	L.S.L * 0.7	U.S.L * 1.3	



#### 6. Label Structure

#### a) Label Structure

Aluminum Bag & Inner Box @ D © D @ D YHRW38 <u>YHRW38</u> Rank SPHCW1HDND25YHRT3P YHRW38 01 SPHCW1HDND25YHRT3P YHRW38 01 Code Lot number OEB1906001/40 OEB1906001/40 OEB1906011/40 OEB1906002/40 OEB1906002/40 OEB1906012/40 UMMMMMMMMMMMM Tray OEB1906003/40 OEB1906013/40 OEB1906003/40 number OEB1906004/40 OEB1906004/40 /Q'ty OEB1906005/40 OEB1906005/40 OEB1906006/40 OEB1906007/40 OEB1906008/40 OEB1906009/40 OEB1906010/40 [Box Label] SAMSUNG SAMSUNG

Note: Denoted rank code and product code above is only an example (see description on page 5)

Rank Code:

- (a)(b): Forward Voltage rank (refer to page 7-10)
- ©d: Chromaticity bin (refer to page 11-12)
- (e) f): Luminous Flux bin (refer to page 7-10)



**Outer Box** 

#### b) Lot Number

The lot number is composed of the following characters:

#### $\bigcirc \bigcirc \diamondsuit \blacklozenge \square \blacksquare \triangle \triangle \triangle / 1 \blacktriangle \blacktriangle \land / xxx PCS$

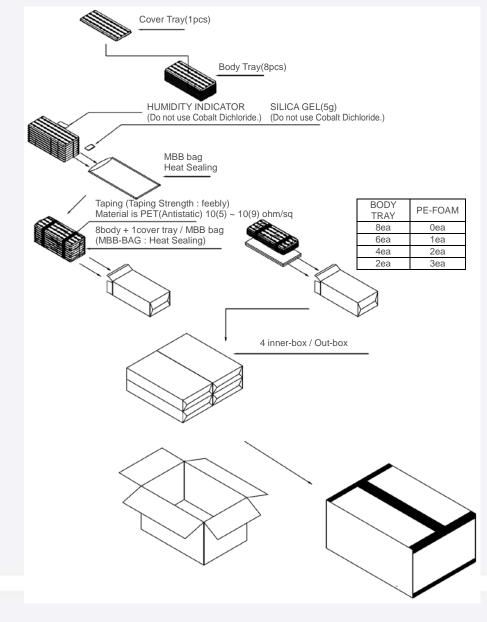
	: Production site (S: Giheung, Korea, G: Tianjin, China)
$\bigcirc$	: L (LED)
$\diamond$	: Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
•	: Year (Y: 2014, Z: 2015, A: 2016,)
	: Month (1~9, A, B, C)
•	: Day (1~9, A, B~V)
$\triangle \triangle \triangle$	: Product serial number (001 ~ 009)
	: Tray number (001 ~ 999)

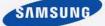


# 7. Packing Structure

Decking metorial	Max. quantity in pcs of COB	Dimension (mm)			
Packing material		Length	Width	Height	Tolerance
Tray	40	322.6	135.9	10.8	1.0
Aluminum Bag	320 (8 trays)	450	230	-	10
PE Foam Pad	-	280	130	10	2
Inner Box	320 (1 aluminum bag)	338	148	55	2
Outer Box	1,280 (4 inner boxes)	351	308	120	5
Pallet	71,680 (56 outer boxes)	1000	1000	130	10

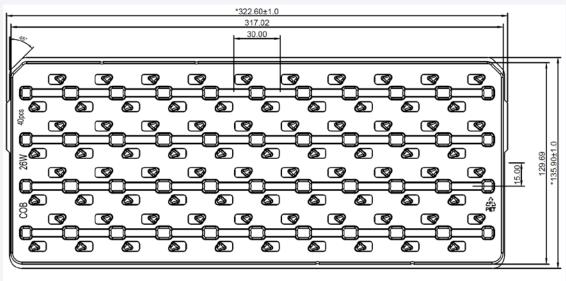
#### a) Packing Structure

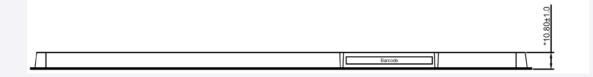




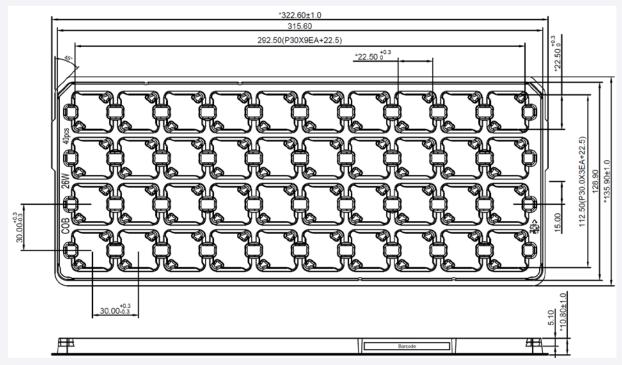
b) Tray

#### ① COVER



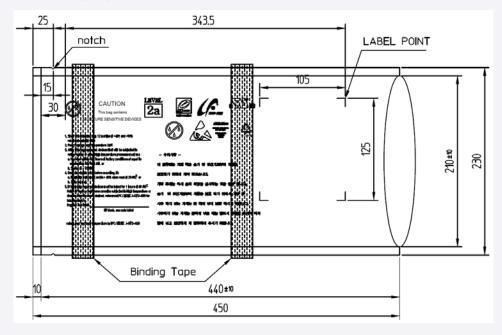


#### **② BODY**





#### c) Aluminum Vinyl Packing Bag



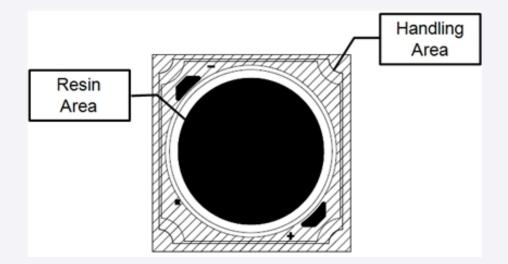
d) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Packing Bag





#### 8. Precautions in Handling & Use

- This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
  a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
  b. Stored at <10 % RH</li>
- 4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 5) Devices require baking before mounting, if humidity card reading is >60 % at  $23 \pm 5$  °C.
- 6) Devices must be baked for 1 hour at  $60 \pm 5$  °C, if baking is required.
- 7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 8) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 9) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.





# Legal and additional information.

#### About Samsung Electronics Co., Ltd.

Samsung Electronics Co., Ltd. inspires the world and shapes the future with transformative ideas and technologies, redefining the worlds of TVs, smartphones, wearable devices, tablets, cameras, digital appliances, printers, medical equipment, network systems and semiconductors. We are also leading in the Internet of Things space through, among others, our Digital Health and Smart Home initiatives. We employ 307,000 people across 84 countries. To discover more, please visit our official website at www.samsung.com and our official blog at global.samsungtomorrow.com.

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